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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/602,673	06/25/2003	Kazuhito Matsukawa	239120US0 DIV	1975	
22850	7590 06/16/2005	EXAMINER			
OBLON, SPIVAK, MCCLELLAND, MAIER & NEUSTADT, P.C.			ERDEM, FAZLI		
1940 DUKE STREET ALEXANDRIA, VA 22314			ART UNIT	PAPER NUMBER	
ALEXANDRI	1, VA 22314		2826	·	
		DATE MAILED: 06/16/2005			

Please find below and/or attached an Office communication concerning this application or proceeding.

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		Application No.	Applicant(s)	<del>()</del>		
Office Action Summary		10/602,673	MATSUKAWA, KAZUHI	то		
		Examiner	Art Unit			
		Fazli Erdem	2826			
Period f	The MAILING DATE of this communication apports or Reply	pears on the cover sheet with the	correspondence address			
THE - Extended after - If the results of the result	MORTENED STATUTORY PERIOD FOR REPL MAILING DATE OF THIS COMMUNICATION. ensions of time may be available under the provisions of 37 CFR 1.1 r SIX (6) MONTHS from the mailing date of this communication. e period for reply specified above is less than thirty (30) days, a repl D period for reply is specified above, the maximum statutory period to ure to reply within the set or extended period for reply will, by statute reply received by the Office later than three months after the mailing and patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be y within the statutory minimum of thirty (30) dwill apply and will expire SIX (6) MONTHS fro to, cause the application to become ABANDON	timely filed  ays will be considered timely.  m the mailing date of this communi  IED (35 U.S.C. § 133).	ication.		
Status						
1)⊠	Responsive to communication(s) filed on 21 M	farch 2005.				
· ·		s action is non-final.				
3)□	Since this application is in condition for alloware closed in accordance with the practice under E	nce except for formal matters, p		its is		
Disposit	tion of Claims					
5)[🛛	Claim(s) 1-4,6,8-12,17 and 18 is/are pending i 4a) Of the above claim(s) is/are withdray Claim(s) 1-4,6 and 8-12 is/are allowed. Claim(s) 18 is/are rejected. Claim(s) is/are objected to. Claim(s) are subject to restriction and/o	wn from consideration.				
Applicat	tion Papers					
9)[	The specification is objected to by the Examine	er.				
10)	))☐ The drawing(s) filed on is/are: a)☐ accepted or b)☐ objected to by the Examiner.					
	Applicant may not request that any objection to the	drawing(s) be held in abeyance. S	ee 37 CFR 1.85(a).			
11)	Replacement drawing sheet(s) including the correct The oath or declaration is objected to by the Ex	* * * *	· ·	• •		
Priority	under 35 U.S.C. § 119					
a)	Acknowledgment is made of a claim for foreign All b) Some * c) None of:  1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority application from the International Bureau See the attached detailed Office action for a list	es have been received. Is have been received in Applica Inity documents have been recei In (PCT Rule 17.2(a)).	ation No ved in this National Stage	e		
Attachmer	• •	A) 🔲 I=1=! 0	ev (DTO 442)			
	ce of References Cited (PTO-892) ce of Draftsperson's Patent Drawing Review (PTO-948)	4) L Interview Summa Paper No(s)/Mail				
3) 🔲 Infor	mation Disclosure Statement(s) (PTO-1449 or PTO/SB/08) er No(s)/Mail Date	5) Notice of Informal 6) Other:	Patent Application (PTO-152)			

Art Unit: 2826

#### **DETAILED ACTION**

## Response to Arguments

Applicant's arguments filed 03/21/2005 have been fully considered but they are not persuasive. Kalkhoran et al. discloses a wavelength selective photodetector where in Fig. 1, silicon dioxide insulating layer 102 divides substrate 102 into layer 108 and 110. Insulating layer 102 extends throughout the substrate 106. Kalkhoran et al. fail to disclose the required semiconductor buried oxide insulation thickness. However, Sadana et al. disclose a defect induced buried oxide for throughput SOI where in Fig. 3 and Claims 1, 6 and 15 the required buried oxide thickness is disclosed. Furthermore, Fig. 2 of Kalkhoran et al. disclose the curve graph of thickness of 10 micrometers for the upper Silicon part of 128. Therefore, according to the Kalkhoran et al., the distance between the upper surface of the substrate and the buried insulating layer 102 is more than 10 micrometers.

#### Allowable Subject Matter

1. Claims 1-4, 6, 8-12 and 17 allowed.

### Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claims 18 rejected under 35 U.S.C. 103(a) as being unpatentable over Kalkhoran et al. (5,726,40) in view of Sadana et al. (6,259,137).

Application/Control Number: 10/602,673

Art Unit: 2826

Regarding Claims 1, 3-5, 7-12 and 17, Kalkhoran et al. discloses a wavelength selective photodetector where in Fig. 1, silicon dioxide insulating layer 102 divides substrate 102 into layer 108 and 110. Insulating layer 102 extends throughout the substrate 106. Kalkhoran et al. fail to disclose the required semiconductor buried oxide insulation thickness. However, Sadana et al. disclose a defect induced buried oxide for throughput SOI where in Fig. 3 and Claims 1, 6 and 15 the required buried oxide thickness is disclosed.

It would have been obvious to one of having ordinary skill in the art at the time the invention was made to include the required buried oxide thickness in Kalkhoran et al. as taught by Sadana et al. in order to have a semiconductor structure with increased performance.

#### Conclusion

3. THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Application/Control Number: 10/602,673

Art Unit: 2826

Page 4

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Fazli Erdem whose telephone number is (571) 272-1914. The examiner can normally be reached on M - F 8:00 - 5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nathan Flynn can be reached on (571) 272-1915. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

FE June 6, 2005

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